	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI2307CDS-T1-GE3</a></p>
	<p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p>
	<p><b>Teil der Beschreibung:</b> MOSFET P-CH 30V 3.5A SOT23-3</p>
	<p><b>Datenblätter:</b>  <a href="#">SI2307CDS-T1-GE3.pdf</a></p>
<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>	<p><b>Lagerzustand:</b> New original, 299028 pcs Stock Available.</p>
<p><b>Lieferung von:</b> Hong Kong</p>	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	<a href="#">SI2307CDS-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET P-CH 30V 3.5A SOT23-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	299028 pcs Stock
Hersteller Standard Vorlaufzeit	32 Weeks
detaillierte Beschreibung	P-Channel 30V 3.5A (Tc) 1.1W (Ta), 1.8W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.1W (Ta), 1.8W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.5A (Tc)
Rds On (Max) @ Id, Vgs	88 mOhm @ 3.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.2nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	340pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2307CDS-T1-GE3TR



































SI2307CDS-T1-GE3 ist neu im Original. Suche SI2307CDS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2307CDS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2307CDS-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI2307CDS</b> VISHAY SI2307CDS VISHAY</p>	 <p><b>SI2307CDS-T1-E3</b> Vishay / Siliconix MOSFET P-CH 30V 3.5A SOT23-3</p>	 <p><b>SI2307CDS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 3.5A SOT23-3</p>	 <p><b>SI2307DL-T1-E3</b> VISHAY VISHAY SOT-323</p>
 <p><b>SI2307DS</b> VISHAY/ SI2307DS VISHAY/</p>	 <p><b>SI2307DS-T1</b> VISHAY SI2307DS-T1 VISHAY</p>	 <p><b>SI2307CDS-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 3.5A SOT23-3</p>	 <p><b>SI2307CDS A7SHB</b> Original SOT-23</p>

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|----------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|
|  SI2305DS-T1      |  SI2305DS-T1-E3   |  SI2305DS-T1-E3   |  SI2305DS-T1-GE3  |  SI2305WCB        |
|  SI2306BDS        |  SI2306BDS-T1     |  SI2306BDS-T1-E3  |  SI2306BDS-T1-E3  |  SI2306BDS-T1-GE3 |
|  SI2306BDS-T1-GE3 |  SI2306CDS-T1-E3  |  SI2306DS         |  SI2306DS-T1      |  SI2306DS-T1-E3   |
|  SI2306DS-T1-GE3  |  SI2306WCA        |  SI2307BDS        |  SI2307BDS-T1-E3  |  SI2307BDS-T1-E3  |
|  SI2307BDS-T1-GE3 |  SI2307BDS-T1-GE3 |  SI2307CDS        |  SI2307CDS-T1-E3  |  SI2307CDS-T1-E3  |
|  SI2307CDS-T1-GE3 |  SI2307DS         |  SI2307DS-T1      |  SI2307DS-T1-E3   |  SI2307DS-T1-GE3  |
|  SI2307DS-T7-E3   |  SI2308BDS        |  SI2308BDS-T1-E3  |  SI2308BDS-T1-E3  |  SI2308BDS-T1-GE3 |
|  SI2308BDS-T1-GE3 |  SI2308DS         |  SI2308DS-T1      |  SI2308DS-T1-E3   |  SI2308DS-T1-E3   |
|  SI2308DS-T1-GE3  |  SI2309BDS-T1-E3  |  SI2309BDS-T1-GE3 |  SI2309CDS-T1-GE3 |  SI2309CDS-T1-GE3 |
|  SI2309DS         |  SI2309DS-T1      |  SI2309DS-T1-E3   |  SI2309DS-T1-E3   |  SI2309DS-T1-GE3  |

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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